1

- 3-State Buffer-Type Outputs Drive Bus **Lines Directly**
- **Bus-Structured Pinout**
- **Package Options Include Plastic** Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Plastic (NT) and Ceramic (JT) DIPs

description

These dual 4-bit D-type latches feature 3-state outputs designed specifically for bus driving. This makes these devices particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The dual 4-bit latches are transparent D-type latches. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs in true form, according to the function table. When LE is low, the outputs are latched. When the clear (CLR) input goes low, the Q outputs go low independently of LE. The outputs are in a high-impedance state when the output-enable (\overline{OE}) input is at a high logic level.

The SN54ALS873B and SN54AS873 are characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ALS873B and SN74AS873A are characterized for operation from 0°C to 70°C.

SN54ALS873B, SN54AS873 JT PACKAGE
SN74ALS873B, SN74AS873A DW OR NT PACKAGE
(TOP VIEW)

	•			
1 <u>CLR</u> [1OE [1D1 [1D2 [1D3 [2D1 [2D2 [2D3 [2D4]	9	σ	24 23 22 21 20 19 18 17 16 15	Vcc 1LE 1Q1 1Q2 1Q3 1Q4 2Q1 2Q2 2Q3
	4		16	2
204 [20E [GND [10 11 12		15 14 13] 204] 2LE] 2CLR
			_	

SN54ALS873B, SN54AS873 ... FK PACKAGE (TOP VIEW)

			1D1	1 <u>0E</u>	1CLR	NC	Vcc	1LE	1Q1		_
	$\ $	τ									
1D2	þ	5	4	3	2	1	28	27		25	1Q2
1D3		6							2	24 🛛	1Q3
1D4	þ	7							2	23[1Q4
NC		8							2	22	NC
2D1	þ	9							2	21	2Q1
2D2		10)						2	20	2Q2
2D3	D.	11							1	9[2Q3
	Γ	ļ	12	13	14	15	16	17	18		
	_		4	1111		$\overline{\mathbf{O}}$			4		
			2D4	2 <u>0</u> E	GNE	NC	CLR	2LE	2Q4		

NC - No internal connection

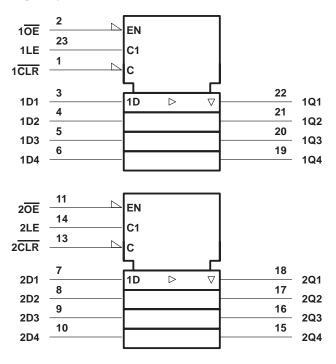
FUNCTION TABLE (each latch)

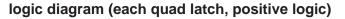
	INPU	JTS		OUTPUT
OE	CLR	LE	D	Q
L	L	Х	Х	L
L	Н	Н	Н	Н
L	Н	Н	L	L
L	Н	L	Х	Q ₀
Н	Х	Х	Х	Z

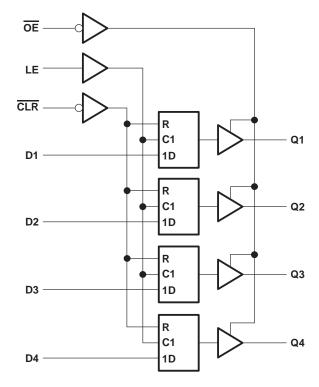
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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logic symbol[†]







[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DW, JT, and NT packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage, V _{CC}	
Input voltage, V	
Voltage applied to a disabled 3-state output	
Operating free-air temperature range, T _A : SN54ALS873B	
SN74ALS873B	0°C to 70°C
Storage temperature range	–65°C to 150°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SNS	4ALS87	3B	SN74ALS873B			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
IOH	High-level output current			-1			-2.6	mA
IOL	Low-level output current			12			24	mA
TA	Operating free-air temperature	-55		125	0		70	°C



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PARAMETER	TERTO	ONDITIONS	SN54ALS873B		SN7	4ALS87	'3B	3 UNIT	
PARAMETER	TEST C	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
VIK	V _{CC} = 4.5 V,	lı = –18 mA			-1.2			-1.2	V
	V_{CC} = 4.5 V to 5.5 V,	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2	2		V _{CC} -2			
VOH	V _{CC} = 4.5 V	$I_{OH} = -1 \text{ mA}$	2.4	3.3					V
	$v_{\rm CC} = 4.5 v$	$I_{OH} = -2.6 \text{ mA}$				2.4	3.2		
		I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
VOL	$V_{CC} = 4.5 V$	I _{OL} = 24 mA					0.35	0.5	v
IOZH	$V_{CC} = 5.5 V,$	V _O = 2.7 V			20			20	μΑ
IOZL	$V_{CC} = 5.5 V,$	$V_{O} = 0.4 V$			-20			-20	μΑ
lj	$V_{CC} = 5.5 V,$	V ₁ = 7 V			0.1			0.1	mA
Iн	$V_{CC} = 5.5 V,$	V _I = 2.7 V			20			20	μΑ
١ _{١L}	V _{CC} = 5.5 V,	V _I = 0.4 V			- 0.2			- 0.2	mA
IO‡	V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA
		Outputs high		11	21		11	21	
ICC	V _{CC} = 5.5 V	Outputs low		16	29		16	29	mA
		Outputs disabled		20	31		20	31	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

[†] All typical values are at V_{CC} = 5 V, $T_A = 25^{\circ}C$.

[‡] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

			SN54AL	S873B	SN74AL	S873B	UNIT
			MIN	MAX	MIN	MAX	UNIT
+	Pulse duration	CLR low	15		15		
t _W		LE high	10		10		ns
t _{su}	Setup time, data before LE \downarrow		10		10		ns
th	Hold time, data after LE \downarrow		7		7		ns



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switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CL R1 = R2 =	c = 4.5 V = 50 pF, = 500 Ω, = 500 Ω, = MIN to			UNIT
			SN54AL	S873B	SN74AL	S873B	
			MIN	MAX	MIN	MAX	
^t PLH	D	Q	2	23	2	14	ns
^t PHL		Q	2	17	2	14	115
^t PLH	LE	Q	8	31	8	22	ns
^t PHL		Q	8	26	8	21	115
^t PHL	CLR	Q	6	27	6	20	ns
^t PZH	OE	Q	4	24	4	18	ns
tPZL	UE			23	4	18	115
^t PHZ	ŌĒ	Q	2	12	2	10	ns
t _{PLZ}	UL UL	Q	2	30	2	15	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage, V _{CC}	
Input voltage, V ₁	
Voltage applied to a disabled 3-state output	
Operating free-air temperature range, T _A : SN54AS873	
SN74AS873A	0°C to 70°C
Storage temperature range	−65°C to 150°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN	154AS87	'3	SN	SN74AS873A		
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
ЮН	High-level output current			-12			-15	mA
IOL	Low-level output current			32			48	mA
TA	Operating free-air temperature	-55		125	0		70	°C



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PARAMETER	TERTO	ONDITIONS	SN	I54AS87	'3	SN	74AS87	3A	UNIT
PARAMETER	TEST C	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
VIK	V _{CC} = 4.5 V,	lj = -18 mA			-1.2			-1.2	V
	$V_{CC} = 4.5 V \text{ to } 5.5 V,$	$I_{OH} = -2 \text{ mA}$	V _{CC} -2	2		V _{CC} -2			
VOH	V _{CC} = 4.5 V	I _{OH} = -12 mA	2.4	3.2					V
	$v_{\rm CC} = 4.5 v$	$I_{OH} = -15 \text{ mA}$				2.4	3.3		
Ve	$\lambda = 45 \lambda$	I _{OL} = 32 mA		0.25	0.5				V
VOL	$V_{CC} = 4.5 V$	I _{OL} = 48 mA					0.35	0.5	v
IOZH	V _{CC} = 5.5 V,	V _O = 2.7 V			50			50	μΑ
I _{OZL}	V _{CC} = 5.5 V,	V _O = 0.4 V			-50			-50	μA
lj –	V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
IН	$V_{CC} = 5.5 V,$	V _I = 2.7 V			20			20	μA
١ _{IL}	V _{CC} = 5.5 V,	V _I = 0.4 V			- 0.5			- 0.5	mA
IO‡	V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	-30		-112	mA
		Outputs high		68	110		68	110	
ICC	$V_{CC} = 5.5 V$	Outputs low		67	109		67	109	mA
		Outputs disabled		80	129		80	129	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

[†] All typical values are at V_{CC} = 5 V, $T_A = 25^{\circ}C$.

[‡]The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

			SN54AS873		SN74AS873A		UNIT	
				MAX	MIN	MAX		
tw*	Pulse duration	CLR low	5		5			
		LE high	6		5		ns	
t _{su} *	$_{su}^*$ Setup time, data before LE \downarrow		2		2		ns	
t _h *	t_h^* Hold time, data after LE \downarrow		4.5		4.5		ns	

* On products compliant to MIL-STD-883, Class B, these parameters are based on characterization data but are not production tested.



SN54ALS873B, SN54AS873, SN74ALS873B, SN74AS873A DUAL 4-BIT D-TYPE LATCHES WITH 3-STATE OUTPUTS SDAS036C – APRIL 1982 – REVISED SEPTEMBER 1994

switching characteristics (see Figure 1)

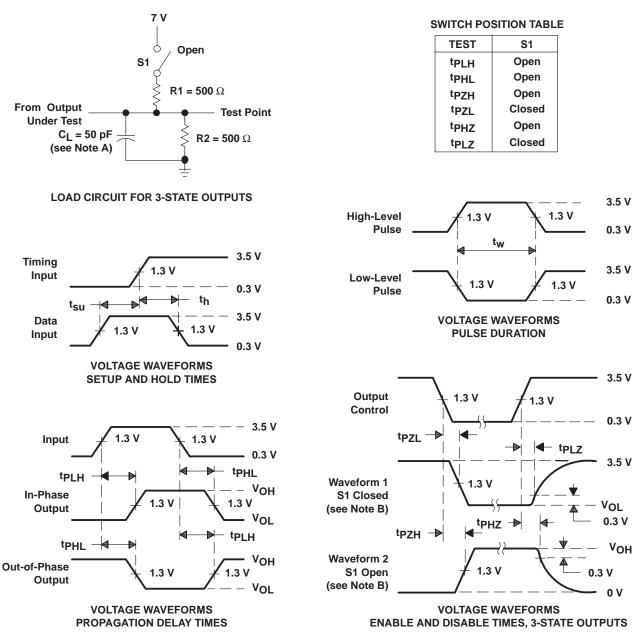
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4.5 V \text{ to } 5.5 V,$ $C_L = 50 \text{ pF},$ $R1 = 500 \Omega,$ $R2 = 500 \Omega,$ $T_A = \text{MIN to MAX}^{\dagger}$				UNIT
			SN54AS873		SN74AS873A		
			MIN	MAX	MIN	MAX	
^t PLH	D	Q	3	9	3	9.5	ns
^t PHL			3	7	3	7.5	
^t PLH	LE	Q	6	14	6	13	ns
^t PHL			4	9	4	7.5	
^t PHL	CLR	Q	3	10	3	9	ns
^t PZH	ŌĒ	Q	2	8	2	6.5	ns
tPZL			4	11	4	10.5	
^t PHZ	ŌĒ	Q	2	8	2	7.5	l ns
t _{PLZ}			2	8.5	2	7.5	

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_Q = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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